



Product Overview

NTD4806N: Power MOSFET 30V 76A 6 mOhm Single N-Channel DPAK

For complete documentation, see the data sheet

Product Description

Power MOSFET 30V 76A 6 mOhm Single N-Channel DPAK

Features

- Low  $R_{DS(on)}$  to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- Optimized Gate Charge to Minimize Switching Losses
- These are Pb-Free Devices

Applications

- CPU Power Delivery
- DC-DC Converters
- Low Side Switching

Part Electrical Specifications

Product	Compliance	Status	Channel Polarity	Configuration	$V_{DS}^{(BR)}$ Min (V)	$V_{GS}^{(th)}$ Max (V)	$V_{GS}^{(th)}$ Max (V)	$I_D$ Max (A)	$P_D$ Max (W)	$r_{DS(on)}$ Max @ $V_{GS} = 2.5V$ (m)	$r_{DS(on)}$ Max @ $V_{GS} = 4.5V$ (m)	$r_{DS(on)}$ Max @ $V_{GS} = 10V$ (m)	$Q_g$ Typ @ $V_{GS} = 4.5V$ (nC)	$Q_g$ Typ @ $V_{GS} = 10V$ (nC)	$Q_{gd}$ Typ @ $V_{GS} = 4.5V$ (nC)	$Q_{rr}$ Typ (nC)	$C_{iss}$ Typ (pF)	$C_{oss}$ Typ (pF)	$C_{rss}$ Typ (pF)	Package Type
NTD4806NT4G	Pb-free Halide free	Active	N-Channel	Single	30	20	2.5	76	68		9.4	6	15	37	7		2142	480	251	DPAK-3

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